

SILICON BRIDGE RECTIFIER

Features

- This series is UL listed under the Recodrized component index ,file number E142814
- •The plastic material used carries UndewritersLaboratory flammability recognition 94V-0
- •Surge overload ratinge to 50 amperes
- •Ideal for printed circuit board application
- •High temperature soldering guaranteed 265 C/10 seconds at 5 ibs(2.3Kg)tension

Mechanical Data

- •Case: DB-S, molded plastic
- •Terminals: plated leads solderable per MIL-STD-202, Method 208
- •Polarity: as marked on case
- Mounting position: Any
- Marking: type number

MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)Single phase,half wave,60 Hz,resistive or inductive load.

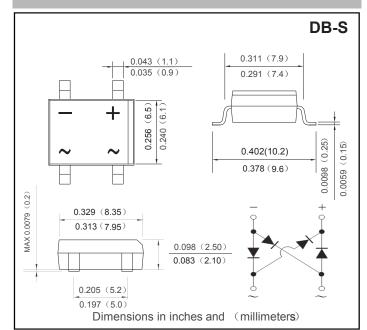
For capacitive load, derate by 20%.

TYPE NUMBER	SYMBOL	DB201S	DB202S	DB203S	DB204S	DB205S	DB206S	DB207S	UNITS
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	Vrrm								
	Vrwm	50	100	200	400	600	800	1000	V
	Vdc								
RMS Reverse Voltage	Vrms	35	70	140	280	420	560	700	V
Average Rectified Output Current @Ta=40	°C IMF(AV)	2.0							А
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSM	50							A
I ² t Rating for Fusing (t < 8.3ms)	²t	10							A ² s
Forward Voltage per element @IF=1.0A	Vfm	1.1							V
Peak Reverse Current@Ta=25℃At Rated DC Blocking Voltage@Ta=125℃	Ir	10 500							uA
Typical Junction Capacitance per leg (2)	CJ	25							pF
Typical Thermal Resistance per leg(1)	Reja	110							°C/W
	Rejl	15							
Operating and Storage Temperature Range	TJ,Tsтg	-55to+150							°C

Note:1. Thermal resistance from junction to ambemt on P.C. board mounting

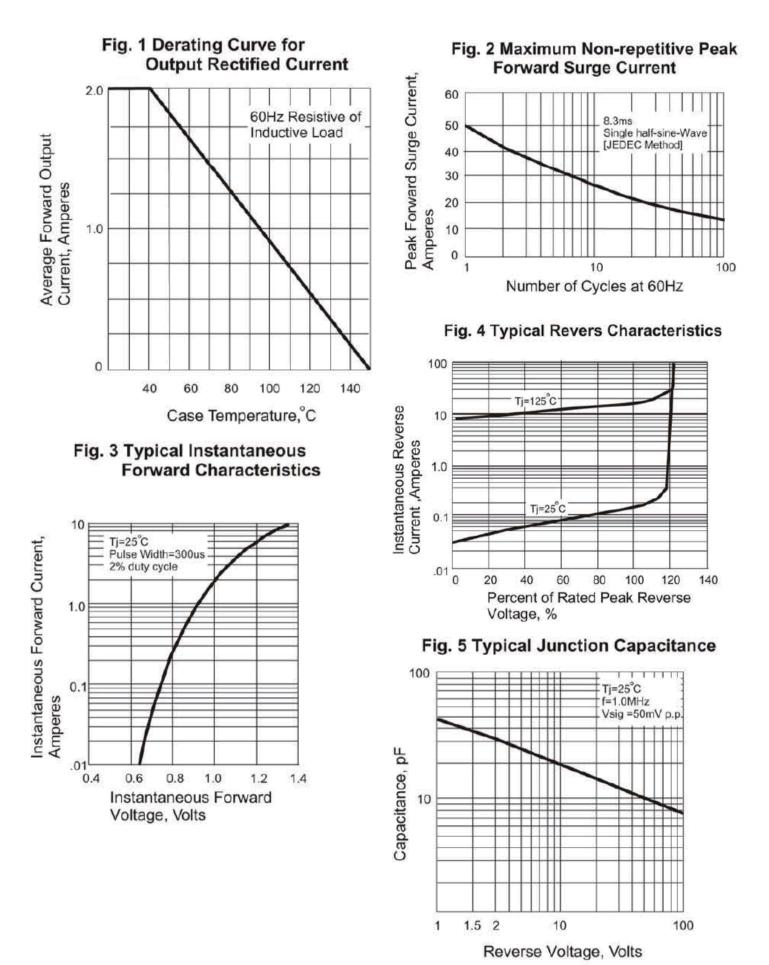
2. Measured at 2.0 MHz and applied reverse voltage of 4.0V D.C.

REVERSE VOLTAGE : 50 --- 1000 V CURRENT: 2.0A





RATINGS AND CHARACTERISTIC CURVES



http://www.hfzt.net